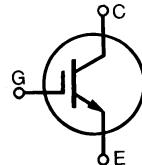


HiPerFAST™ IGBT

IXGH 28N90B IXGT 28N90B

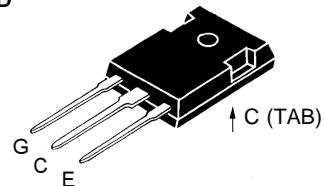
Preliminary data sheet

| | | | |
|----------------|---|-----|----|
| V_{CES} | = | 900 | V |
| I_{C25} | = | 51 | A |
| $V_{CE(SAT)}$ | = | 2.7 | V |
| $t_{fi(typl)}$ | = | 130 | ns |

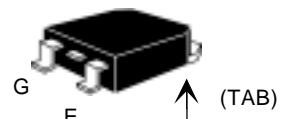


| Symbol | Test Conditions | Maximum Ratings | | |
|---|---|----------------------------------|------------------|---|
| V_{CES} | $T_J = 25^\circ\text{C}$ to 150°C | 900 | V | |
| V_{CGR} | $T_J = 25^\circ\text{C}$ to 150°C ; $R_{GE} = 1 \text{ M}\Omega$ | 900 | V | |
| V_{GES} | Continuous | ± 20 | V | |
| V_{GEM} | Transient | ± 30 | V | |
| I_{C25} | $T_c = 25^\circ\text{C}$ | 51 | A | |
| I_{C110} | $T_c = 110^\circ\text{C}$ | 28 | A | |
| I_{CM} | $T_c = 25^\circ\text{C}$, 1 ms | 120 | A | |
| SSOA (RBSOA) | $V_{GE} = 15 \text{ V}$, $T_{VJ} = 125^\circ\text{C}$, $R_G = 10 \Omega$ Clamped inductive load, $L = 100 \mu\text{H}$ | $I_{CM} = 56$ @ $0.8 V_{CES}$ | A | |
| P_c | $T_c = 25^\circ\text{C}$ | 200 | W | |
| T_J | | -55 ... +150 | $^\circ\text{C}$ | |
| T_{JM} | | 150 | $^\circ\text{C}$ | |
| T_{stg} | | -55 ... +150 | $^\circ\text{C}$ | |
| Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s | | 300 | $^\circ\text{C}$ | |
| M_d | Mounting torque (M3) | 1.13/10Nm/lb.in. | | |
| Weight | | TO-247 AD | 6 | g |
| | | TO-247 SMD | 4 | g |

TO-247 AD
(IXGH)



TO-268 (D3)
(IXGT)



G = Gate,
E = Emitter,
C = Collector,
TAB = Collector

Features

- International standard packages
JEDEC TO-268 surface
mountable and JEDEC TO-247 AD
- High current handling capability
- Latest generation HDMOS™ process
- MOS Gate turn-on
 - drive simplicity

Applications

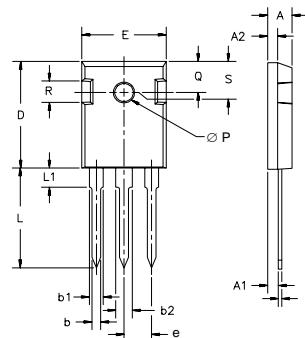
- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies

Advantages

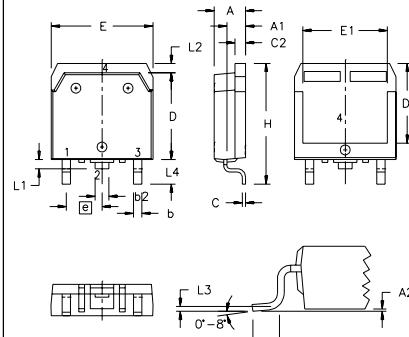
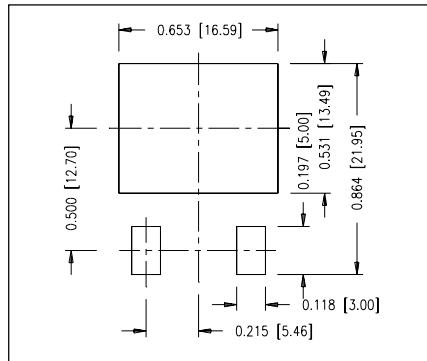
- Space savings (two devices in one package)
- High power density
- Suitable for surface mounting
- Switching speed for high frequency applications
- Easy to mount with 1 screw, TO-247 (isolated mounting screw hole)

| Symbol | Test Conditions | Characteristic Values | | |
|---------------|--|--|------|---------------------------|
| | | ($T_J = 25^\circ\text{C}$, unless otherwise specified) | min. | typ. |
| BV_{CES} | $I_C = 250 \mu\text{A}$, $V_{GE} = 0 \text{ V}$ | 900 | | V |
| $V_{GE(th)}$ | $I_C = 250 \mu\text{A}$, $V_{CE} = V_{GE}$ | 2.5 | | V |
| I_{CES} | $V_{CE} = V_{CES}$ $V_{GE} = 0 \text{ V}$ | $T_J = 25^\circ\text{C}$ $T_J = 150^\circ\text{C}$ | | $500 \mu\text{A}$ 5 mA |
| I_{GES} | $V_{CE} = 0 \text{ V}$, $V_{GE} = \pm 20 \text{ V}$ | | | $\pm 100 \text{ nA}$ |
| $V_{CE(sat)}$ | $I_C = I_{C110}$, $V_{GE} = 15 \text{ V}$ | 2.2 | 2.7 | V |

| Symbol | Test Conditions | Characteristic Values | | | |
|--|---|--|------|------|------|
| | | ($T_j = 25^\circ\text{C}$, unless otherwise specified) | min. | typ. | max. |
| g_{fs} | $I_c = I_{C110}$; $V_{CE} = 10\text{ V}$, Pulse test, $t \leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$ | 20 | 32 | S | |
| C_{les} C_{oes} C_{res} | $V_{CE} = 25\text{ V}$, $V_{GE} = 0\text{ V}$, $f = 1\text{ MHz}$ | 3200 | | pF | |
| | | 160 | | pF | |
| | | 32 | | pF | |
| Q_g Q_{ge} Q_{gc} | $I_c = I_{C110}$, $V_{GE} = 15\text{ V}$, $V_{CE} = 0.5\text{ V}_{CES}$ | 100 | 150 | nC | |
| | | 18 | 28 | nC | |
| | | 40 | 70 | nC | |
| $t_{d(on)}$ t_{ri} $t_{d(off)}$ t_{fl} E_{off} | Inductive load, $T_j = 25^\circ\text{C}$ $I_c = I_{C110}$, $V_{GE} = 15\text{ V}$ $V_{CE} = 0.8\text{ }V_{CES}$, $R_G = R_{off} = 4.7\text{ }\Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) $> 0.8 \cdot V_{CES}$, higher T_j or increased R_G | 30 | | ns | |
| | | 30 | | ns | |
| | | 100 | 170 | ns | |
| | | 130 | 220 | ns | |
| | | 1.2 | 2 | mJ | |
| $t_{d(on)}$ t_{ri} E_{on} $t_{d(off)}$ t_{fl} E_{off} | Inductive load, $T_j = 125^\circ\text{C}$ $I_c = I_{C110}$, $V_{GE} = 15\text{ V}$ $V_{CE} = 0.8\text{ }V_{CES}$, $R_G = R_{off} = 4.7\text{ }\Omega$ Remarks: Switching times may increase for V_{CE} (Clamp) $> 0.8 \cdot V_{CES}$, higher T_j or increased R_G | 30 | | ns | |
| | | 35 | | ns | |
| | | 0.3 | | mJ | |
| | | 280 | | ns | |
| | | 190 | | ns | |
| R_{thJC} R_{thCK} | TO-247 | 0.25 | 0.62 | KW | KW |

TO-247 AD Outline


| Dim. | Millimeter | | Inches | |
|----------------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.7 | 5.3 | .185 | .209 |
| A ₁ | 2.2 | 2.54 | .087 | .102 |
| A ₂ | 2.2 | 2.6 | .059 | .098 |
| b | 1.0 | 1.4 | .040 | .055 |
| b ₁ | 1.65 | 2.13 | .065 | .084 |
| b ₂ | 2.87 | 3.12 | .113 | .123 |
| C | .4 | .8 | .016 | .031 |
| D | 20.80 | 21.46 | .819 | .845 |
| E | 15.75 | 16.26 | .610 | .640 |
| e | 5.20 | 5.72 | .205 | .225 |
| L | 19.81 | 20.32 | .780 | .800 |
| L ₁ | | 4.50 | | .177 |
| ØP | 3.55 | 3.65 | .140 | .144 |
| Q | 5.89 | 6.40 | 0.232 | 0.252 |
| R | 4.32 | 5.49 | .170 | .216 |
| S | 6.15 | BSC | 242 | BSC |

TO-268 Outline

Min Recommended Footprint


| SYM | INCHES | | MILLIMETERS | |
|----------------|--------|------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .193 | .201 | 4.90 | 5.10 |
| A ₁ | .106 | .114 | 2.70 | 2.90 |
| A ₂ | .001 | .010 | 0.02 | 0.25 |
| b | .045 | .057 | 1.15 | 1.45 |
| b ₂ | .075 | .083 | 1.90 | 2.10 |
| C | .016 | .026 | 0.40 | 0.65 |
| C ₂ | .057 | .063 | 1.45 | 1.60 |
| D | .543 | .551 | 13.80 | 14.00 |
| D ₁ | .488 | .500 | 12.40 | 12.70 |
| E | .624 | .632 | 15.85 | 16.05 |
| E ₁ | .524 | .535 | 13.30 | 13.60 |
| e | .215 | BSC | 5.45 | BSC |
| H | .736 | .752 | 18.70 | 19.10 |
| L | .094 | .106 | 2.40 | 2.70 |
| L ₁ | .047 | .055 | 1.20 | 1.40 |
| L ₂ | .039 | .045 | 1.00 | 1.15 |
| L ₃ | .010 | BSC | 0.25 | BSC |
| L ₄ | .150 | .161 | 3.80 | 4.10 |

IXYS reserves the right to change limits, test conditions, and dimensions.

 IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,881,106 5,017,508 5,049,961 5,187,117 5,486,715
 4,850,072 4,931,844 5,034,796 5,063,307 5,237,481 5,381,025

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